

b) Amendments to the Claims

Kindly cancel claims 11, 12 and 14-22 without prejudice or disclaimer of subject matter. Please amend claims 23 and 24 and add new claims 25 and 26 as follows. A detailed listing of all the claims that are or were in the application follows.

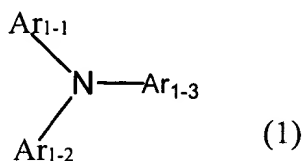
Claims 1-22 (Cancelled)

23. (Currently Amended) A process cartridge mountable to and detachable from an electrophotographic apparatus having an exposure means comprising a semiconductor laser having an oscillation wavelength of 380 to 500 nm as an exposure light source comprising:

an electrophotographic photosensitive member; and

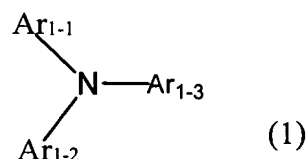
at least one means selected from a charging means, a developing means and a cleaning means, the electrophotographic photosensitive member being integrally supported by said at least one means;

wherein the electrophotographic photosensitive member comprises a conductive substrate, a charge-generating layer formed thereon, and a charge transport layer formed thereon, the charge transport layer having a transmittance of at least 30% for the semiconductor laser light, wherein the charge transport layer contains a charge transfer material represented by the following formula (1):



wherein each of Ar₁₋₁, Ar₁₋₂ and Ar₁₋₃ is ~~a substituted or~~ an unsubstituted phenyl group or a phenyl group substituted with a substituent selected from the group consisting of alkyl group, alkoxy group, halogen atom, aralkyl group, acyl group, haloalkyl group, cyano group, nitro group, phenylcarbamoyl group, carboxy group and hydroxy group.

24. (Currently Amended) An electrophotographic apparatus comprising
 an electrophotographic photosensitive member;
 a charging means;
 an exposure means;
 a developing means; and
 a transfer means;
 wherein the exposure means comprises a semiconductor laser having
 an oscillation wavelength of 380 to 500 nm as an exposure light source, and
 the electrophotographic photosensitive member comprises a
 conductive substrate, a charge-generating layer formed thereon, and a charge transport
 layer formed thereon, the charge transport layer having a transmittance of at least 30% for
 the semiconductor laser light, wherein the charge transport layer contains a charge transfer
 material represented by the following formula (1):

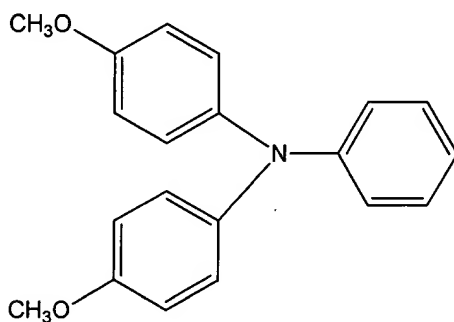


wherein each of Ar₁₋₁, Ar₁₋₂ and Ar₁₋₃ is ~~a substituted or~~ an unsubstituted phenyl group or a phenyl group substituted with a substituent selected from

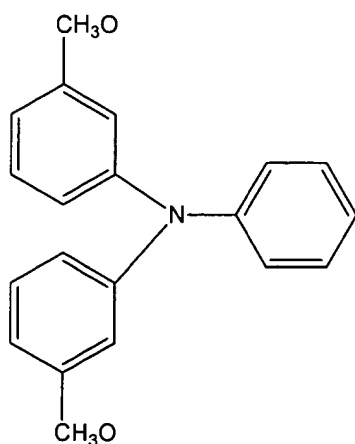
the group, consisting of alkyl group, alkoxy group, halogen atom, aralkyl group, acyl group, haloalkyl group, cyano group, nitro group, phenylcarbamoyl group, carboxy group and hydroxy group.

25. (New) A process cartridge according to claim 23, wherein the charge transfer material is selected from the group consisting of Compound No. 1-6, Compound No. 1-7, Compound No. 1-9 and Compound No. 1-10 as follows:

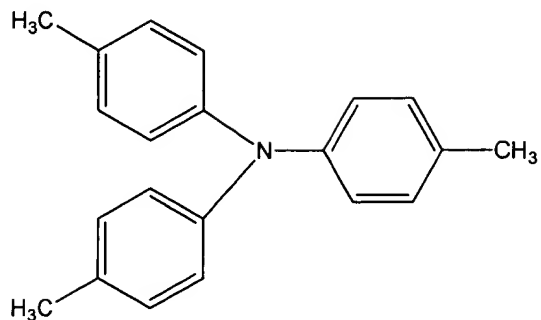
Compound No. 1-6



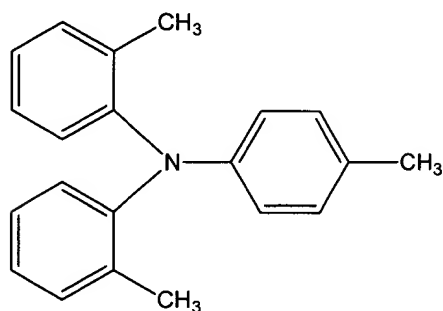
Compound No. 1-7



Compound No. 1-9

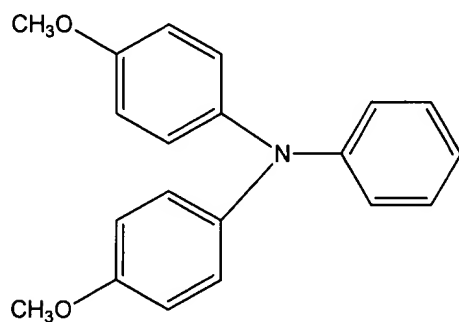


Compound No. 1-10

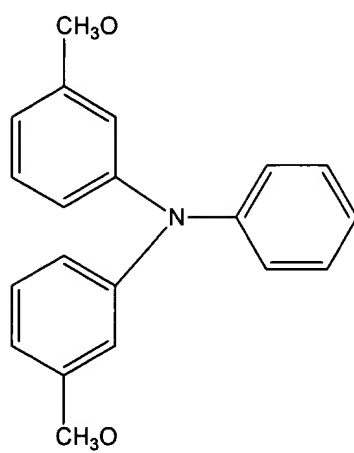


26. (New) An electrophotographic apparatus according to claim 24, wherein the charge transfer material is selected from the group consisting of Compound No. 1-6, Compound No. 1-7, Compound No. 1-9 and Compound No. 1-10 as follows:

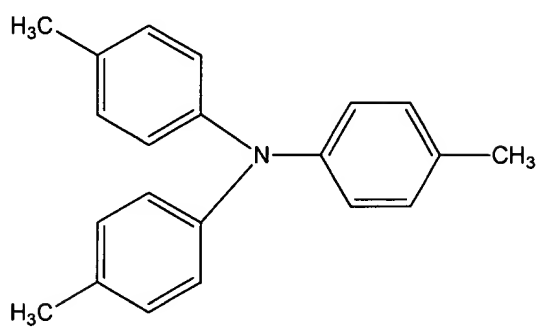
Compound No. 1-6



Compound No. 1-7



Compound No. 1-9



Compound No. 1-10

